

Drop-In

Monolithic Amplifier

DC-3 GHz

Product Features

- DC-3 GHz
- Single voltage supply
- Internally matched to 50 ohms
- Unconditionally stable
- Low performance variation over temperature
- Transient protected
- Aqueous washable
- Protected By US Patent 6,943,629

Typical Applications

- Cellular/ PCS/ 3G Base Station
- CATV, Cable Modem & DBS
- Fixed Wireless & WLAN
- Microwave Radio & Test Equipment



ERA-3+

CASE STYLE: VV105
PRICE: \$1.67 ea. QTY. (30)

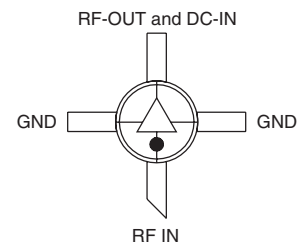
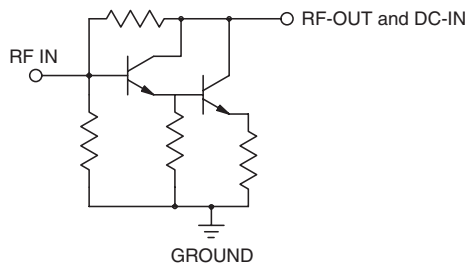
+ RoHS compliant in accordance with EU Directive (2002/95/EC)

The +Suffix has been added in order to identify RoHS Compliance. See our web site for RoHS Compliance methodologies and qualifications.

General Description

ERA-3+ (RoHS compliant) is a wideband amplifier offering high dynamic range. It has repeatable performance from lot to lot. It is enclosed in a Micro-X package. ERA-3+ uses Darlington configuration and is fabricated using InGaP HBT technology. Expected MTBF is 10,000 years at 85°C case temperature.

simplified schematic and pin description



Function	Pin Number	Description
RF IN	1	RF input pin. This pin requires the use of an external DC blocking capacitor chosen for the frequency of operation.
RF-OUT and DC-IN	3	RF output and bias pin. DC voltage is present on this pin; therefore a DC blocking capacitor is necessary for proper operation. An RF choke is needed to feed DC bias without loss of RF signal due to the bias connection, as shown in "Recommended Application Circuit".
GND	2,4	Connections to ground. Use via holes as shown in "Suggested Layout for PCB Design" to reduce ground path inductance for best performance.

Electrical Specifications at 25°C and 35mA, unless noted

Parameter	Min.	Typ.	Max.	Units	Cpk	
Frequency Range*	DC		3	GHz		
Gain	f=0.1 GHz f=1 GHz f=2 GHz f=3 GHz	21 21 17.6 15.4	22.1 21 18.7 16.4	24.3	dB	≥ 1.5
Magnitude of Gain Variation versus Temperature (values are negative)	f=0.1 GHz f=1 GHz f=2 GHz f=3 GHz		0.0045 0.0051 0.0059 0.0064	0.009 0.010 0.012 0.013	dB/°C	
Input Return Loss	f=0.1 GHz f=1 GHz f=2 GHz f=3 GHz		30 19 18 18		dB	
Output Return Loss	f=0.1 GHz f=1 GHz f=2 GHz f=3 GHz		21 17 17 17		dB	
Reverse Isolation	f=2 GHz	21	24		dB	
Output Power @ 1 dB compression	f=0.1 GHz f=1 GHz f=2 GHz f=3 GHz		12.5 12.1 12.5 10.5		dBm	≥ 1.5
Saturated Output Power (at 3dB compression)	f=0.1 GHz f=1 GHz f=2 GHz f=3 GHz		13.6 13.3 13.1 12.1		dBm	
Output IP3	f=0.1 GHz f=1 GHz f=2 GHz f=3 GHz	24 24 23 21	27 27 26 24		dBm	≥ 1.5
Noise Figure	f=0.1 GHz f=1 GHz f=2 GHz f=3 GHz		2.7 2.6 2.8 2.9		dB	≥ 1.5
Group Delay	f=2 GHz		80		psec	
Recommended Device Operating Current			35		mA	
Device Operating Voltage		3.0	3.2	3.4	V	≥ 1.5
Device Voltage Variation vs. Temperature at 35mA			-2.3		mV/°C	
Device Voltage Variation vs. Current at 25°C			3.6		mV/mA	
Thermal Resistance, junction-to-case ¹			181		°C/W	

*Guaranteed specification DC-3 GHz. Low frequency cut off determined by external coupling capacitors.

Absolute Maximum Ratings

Parameter	Ratings
Operating Temperature*	-45°C to 85°C
Storage Temperature	-65°C to 150°C
Operating Current	75mA
Power Dissipation	330mW
Input Power	13dBm

Note: Permanent damage may occur if any of these limits are exceeded.

These ratings are not intended for continuous normal operation.

¹Case is defined as ground leads.

*Based on typical case temperature rise 5°C above ambient.

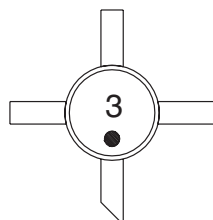


For detailed performance specs & shopping online see web site

P.O. Box 350166, Brooklyn, New York 11235-0003 (718) 934-4500 Fax (718) 332-4661 The Design Engineers Search Engine Provides ACTUAL Data Instantly at minicircuits.com

Notes: 1. Performance and quality attributes and conditions not expressly stated in this specification sheet are intended to be excluded and do not form a part of this specification sheet. 2. Electrical specifications and performance data contained herein are based on Mini-Circuit's applicable established test performance criteria and measurement instructions. 3. The parts covered by this specification sheet are subject to Mini-Circuit's standard limited warranty and terms and conditions (collectively, "Standard Terms"); Purchasers of this part are entitled to the rights and benefits contained therein. For a full statement of the Standard Terms and the exclusive rights and remedies thereunder, please visit Mini-Circuits' website at www.minicircuits.com/MCLStore/terms.jsp.

Product Marking



Additional Detailed Technical Information

Additional information is available on our web site. To access this information enter the model number on our web site home page.

Performance data, graphs, s-parameter data set (.zip file)

Case Style: VV105

Plastic micro-x, .085 body diameter, lead finish: tin/silver/nickel

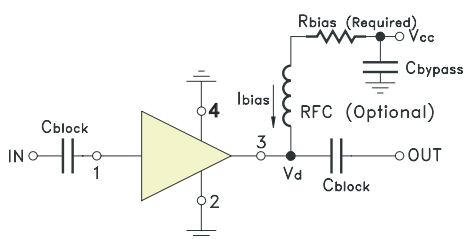
Tape & Reel: F20

Suggested Layout for PCB Design: PL-261

Evaluation Board: TB-431-3+

Environmental Ratings: ENV08T2

Recommended Application Circuit



Test Board includes case, connectors, and components (in bold) soldered to PCB

R BIAS	
Vcc	"1%" Res. Values (ohms) for Optimum Biasing
7	107
8	133
9	162
10	191
11	221
12	251
13	280
14	309
15	340
16	365
17	392
18	422
19	453
20	475

ESD Rating

Human Body Model (HBM): Class 1A (250 v to < 500 v) in accordance with ANSI/ESD STM 5.1 - 2001

Machine Model (MM): Class M1 (< 100 v) in accordance with ANSI/ESD STM 5.2 - 1999

MSL Rating

Moisture Sensitivity: MSL1 in accordance with IPC/JEDECJ-STD-020C

No.	Test Required	Condition	Standard	Quantity
1	Visual Inspection	Low Power Microscope Magnification 40x	MIP-IN-0003 (MCT spec)	45 units
2	Electrical Test	Room Temperature	SCD (MCL spec)	45 units
3	SAM Analysis	Less than 10% growth in term of delamination	J-Std-020C (Jedec Standard)	45 units
4	Moisture Sensitivity Level 1	Bake at 125°C for 24 hours Soak at 85°C/85%RH for 168 hours Reflow 3 cycles at 260°C peak	J-Std-020C (Jedec Standard)	45 units

MSL Test Flow Chart

